

Description

The device is based on a proprietary technology that achieves the best in class V_F/I_R trade-off for a given silicon surface. This 100 V rectifier has been optimized for use in confined applications where both efficiency and thermal performance are key. With a lower dependency of leakage current (I_R) and forward voltage (V_F) in function of temperature, the thermal runaway risk is reduced. It is highly recommended to be used in adapters and chargers.

Table 1: Device summary

Symbol	Value
$I_{F(AV)}$	20 A
V_{RRM}	100 V
V_F (max.)	0.415 V
I_R (max.)	140 μ A
T_j (max.)	175 °C

Features

- ST advanced rectifier process
- Stable leakage current over reverse voltage
- Reduced leakage current
- Low forward voltage drop
- High frequency operation
- Insulated package TO-220FPAB :
 - Insulated voltage : 2000 V_{RMS} sine

1 Characteristics

Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified, anode terminals short circuited)

Symbol	Parameter		Value	Unit	
V_{RRM}	Repetitive peak reverse voltage		100	V	
$I_{F(RMS)}$	Forward rms current		40	A	
$I_{F(AV)}$	Average forward current $\delta = 0.5$, square wave	TO-220AB, DPAK, IPAK	$T_C = 155\text{ °C}$	20	A
		TO-220FPAB	$T_C = 110\text{ °C}$		A
I_{FSM}	Surge non repetitive forward current	TO-220AB, TO-220FPAB	$t_p = 10\text{ ms}$ sinusoidal	250	A
		DPAK, IPAK			150
T_{stg}	Storage temperature range		-65 to +175	°C	
T_j	Maximum operating junction temperature ⁽¹⁾		+175	°C	

Notes:

⁽¹⁾ $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 3: Thermal resistance parameters

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220AB, DPAK, IPAK	1	°C/W
		TO-220FPAB	3.8	

Table 4: Static electrical characteristics, anode terminals short circuited

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$	-		140	μA
		$T_j = 125\text{ °C}$		-	8	16	
		$T_j = 125\text{ °C}$	$V_R = 70\text{ V}$	-	4	7	mA
$V_F^{(2)}$	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 2\text{ A}$	-	0.370	0.415	V
		$T_j = 125\text{ °C}$		-	0.315	0.365	
		$T_j = 25\text{ °C}$	$I_F = 5\text{ A}$	-	0.455	0.515	
		$T_j = 125\text{ °C}$		-	0.450	0.510	
		$T_j = 25\text{ °C}$	$I_F = 10\text{ A}$	-	0.580	0.655	
		$T_j = 125\text{ °C}$		-	0.550	0.605	
		$T_j = 125\text{ °C}$		$I_F = 20\text{ A}$	-	0.640	

Notes:

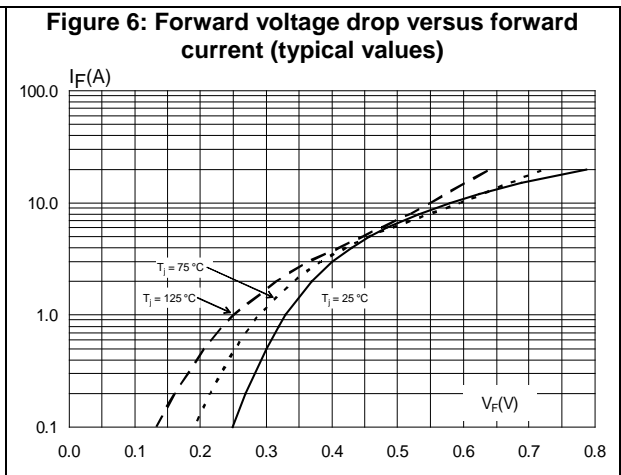
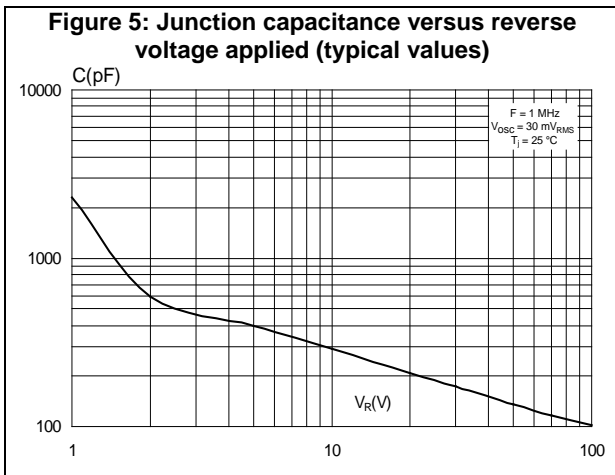
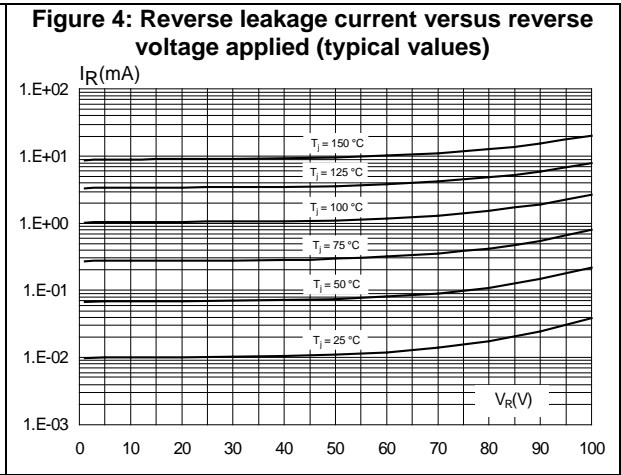
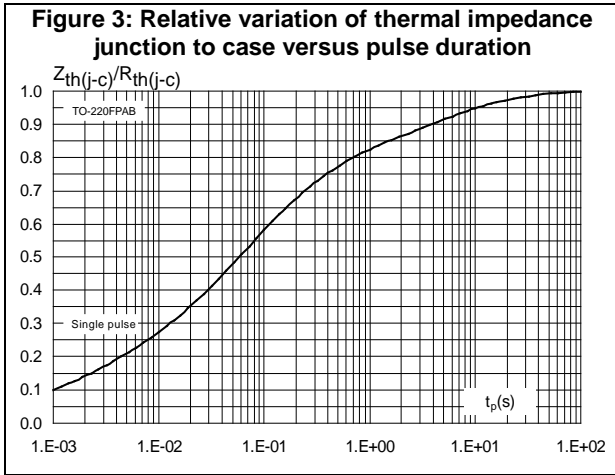
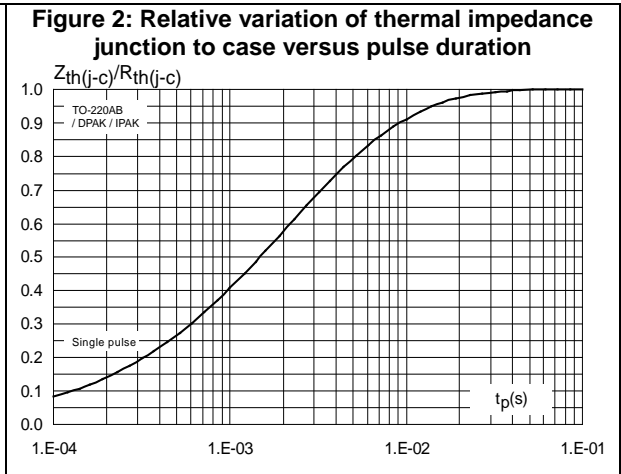
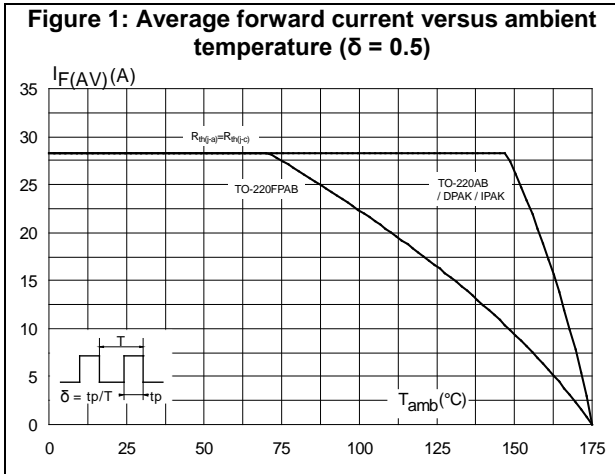
⁽¹⁾Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$

⁽²⁾Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.415 \times I_{F(AV)} + 0.019 I_{F(RMS)}^2$$

1.1 Characteristics (curves)



3 Ordering information

Table 9: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
FERD20H100STS	FD20H100STS	TO-220AB	1.38 g	50	Tube
FERD20H100SFP	FD20H100SFP	TO-220FPAB	1.7 g	50	Tube
FERD20H100SB-TR	FD20 H100S	DPAK	0.35 g	75	Tape and reel
FERD20H100SH	FD20 H100S	IPAK	0.32 g	2500	Tube

4 Revision history

Table 10: Document revision history

Date	Revision	Changes
08-Mar-2016	1	Initial release.
09-May-2016	2	Update of document title.